

Millimeter-wave load-pull techniques

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Millimeter-wave load-pull techniques

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ETH Zürich

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IEEE 1-6 June 2014, Tampa Bay, FL MTT-S

Outline

- ▶ Introduction
 - ▶ Basics of large signal characterization
 - ▶ Applications
- ▶ Large Signal Characterization at high frequency
 - ▶ Existing solution examples
 - ▶ Pros and cons
- ▶ A W-band on-wafer load-pull system
 - ▶ Block scheme
 - ▶ Calibration and accuracy verification
- ▶ Measurement examples
- ▶ Conclusions

Large signal Characterization

| Basics | Applications |
|-----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|-------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| <ul style="list-style-type: none"> ▶ Linear characterization (small signal) provides full information as long as the device under test (DUT) can be considered linear <ul style="list-style-type: none"> ▶ e.g. passive components, transmission lines ▶ Active devices show nonlinear behavior when excited in realistic (large signal) conditions | <ul style="list-style-type: none"> ▶ Many applications require measuring a few device performances in CW, while exciting its nonlinearities ▶ Examples: <ul style="list-style-type: none"> ▶ Performance/technology evaluation ▶ Circuit design ▶ Large signal models refinement ▶ Reliability/failure tests ▶ Production tests |
| <ul style="list-style-type: none"> ▶ The extension of S-parameters to X-parameters might be too complicated ▶ What information do we really need? | |

Introduction

Large signal characterization

A W-band on-wafer load-pull system

Measurement examples

Basics of Large signal Characterization

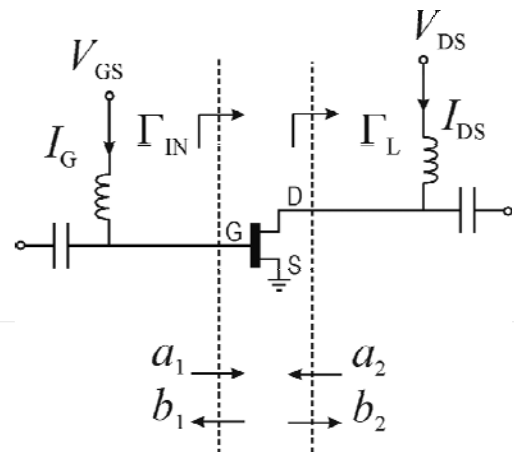
- ▶ We focus on the simplest example: a two port active device (a transistor in common source configuration) fed with a single CW tone @ f_0

- ▶ Interesting performances:

- ▶ DC power, $P_{DC} = V_{GS} I_G + V_{DS} I_D$
- ▶ Output power: $P_{OUT} = |b_2|^2 - |a_2|^2 @ f_0, 2f_0, \dots, nf_0$
- ▶ Gain = $P_{OUT}/P_{IN} @ f_0$
- ▶ Power added efficiency, $PAE = (P_{OUT} - P_{IN})/P_{DC} @ f_0$

- ▶ Influence parameters:

- ▶ Bias point (DC supply)
- ▶ Frequency f_0
- ▶ Input power: $P_{IN} = |a_1|^2 - |b_1|^2$
- ▶ $\Gamma_L = a_2/b_2 @ f_0, 2f_0, \dots, nf_0$

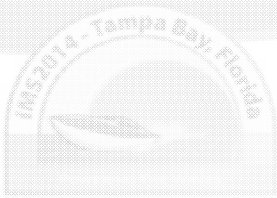


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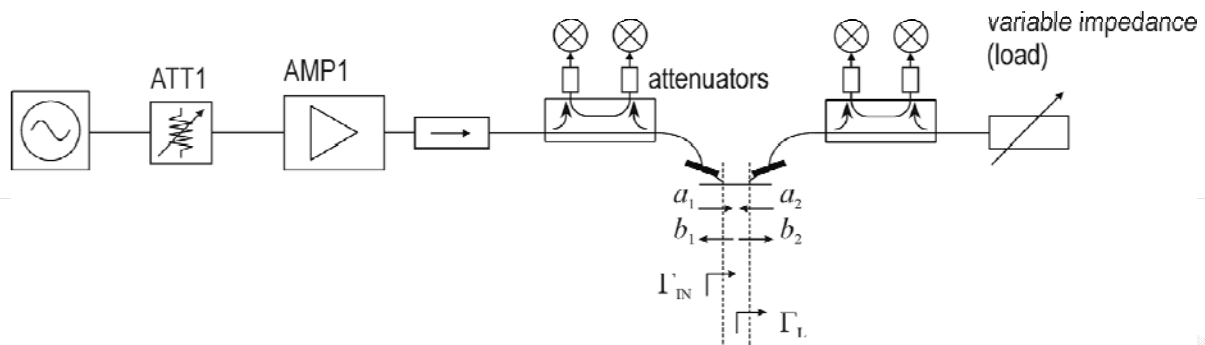
A W-band on-wafer load-pull system

Measurement examples



Load-pull measurements

- ▶ A simplified block scheme of an **on-wafer** load-pull measurement system
- ▶ On-wafer “environment” adds complications
 - ▶ calibration
 - ▶ additional losses

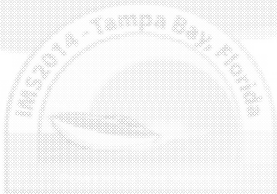


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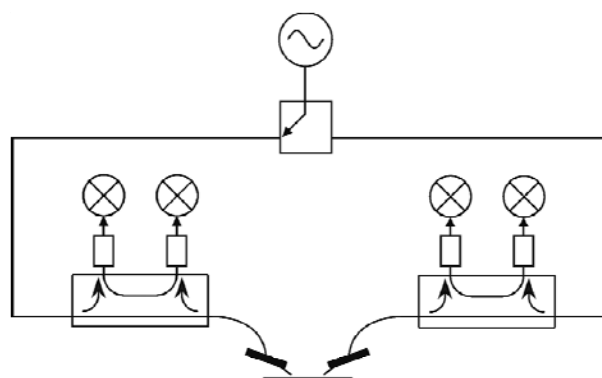
A W-band on-wafer
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Load-pull calibration – vector calibration

- ▶ Vector “VNA-like” calibration



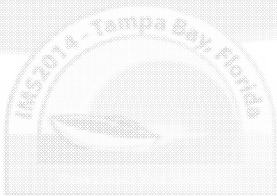
On-wafer or
calibration substrate
standards

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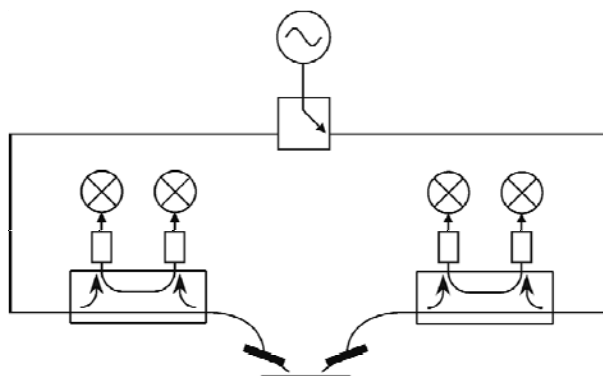
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Load-pull calibration – vector calibration

► Vector “VNA-like” calibration



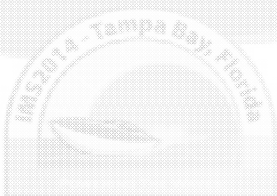
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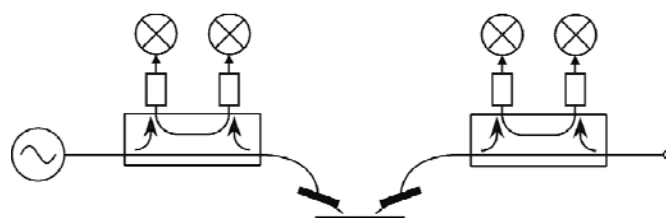
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Load-pull calibration – power calibration

► Power calibration



WG or coax
standards +
power meter

On-wafer or
calibration substrate
thru

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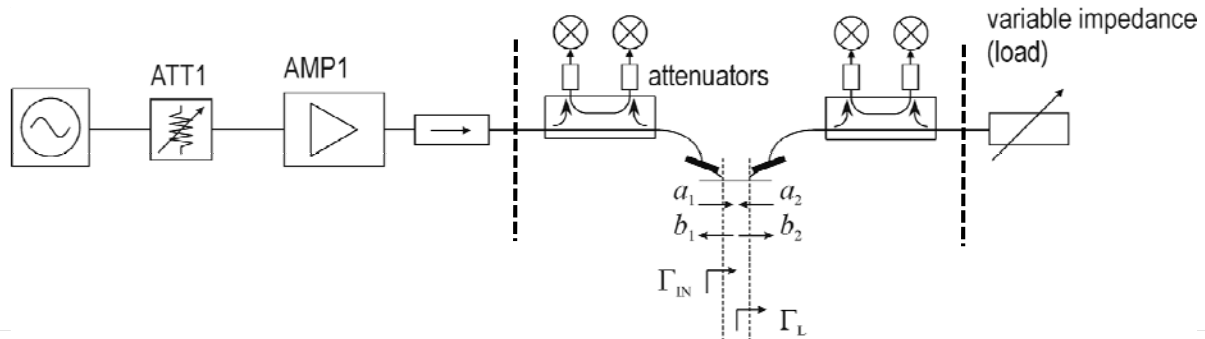
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Load-pull calibration

- ▶ After calibration it is possible to modify the set up at the right of reflectometer 2 and at the left of reflectometer 1, without affecting calibration



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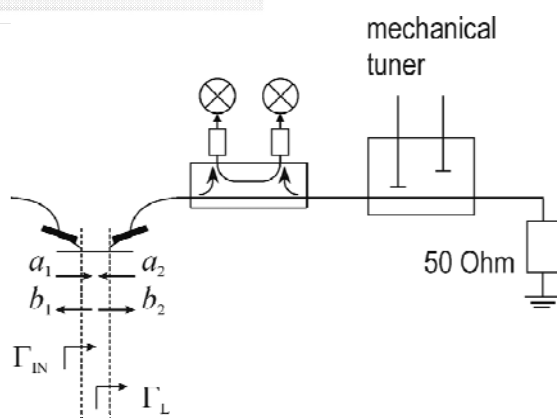
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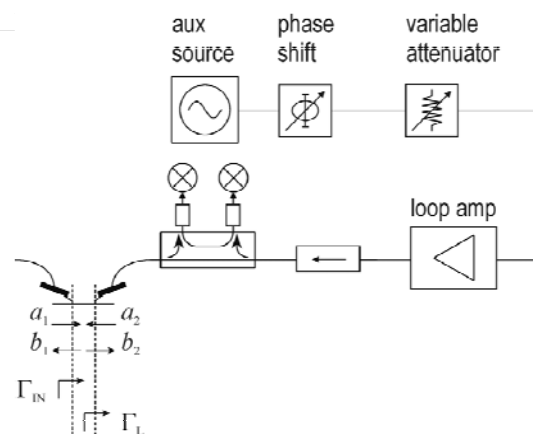
Solutions for tunable loads

Mechanical Tuners



- ▶ Main issue: gamma limitation
 - ▶ Losses cannot be compensated
 - ▶ 2.5 dB losses reduce $|\Gamma|=1$ to $|\Gamma|=0.56$
 - ▶ 0.2 dB losses reduce $|\Gamma|=1$ to $|\Gamma|=0.95$

Active Load – open loop



- ▶ Main issue: gamma varies with P_{OUT}
 - ▶ Compensated by iterations

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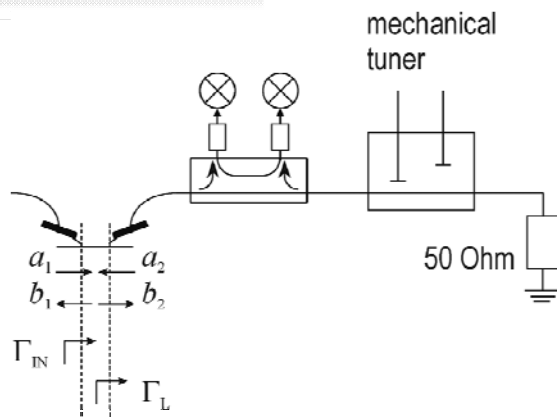
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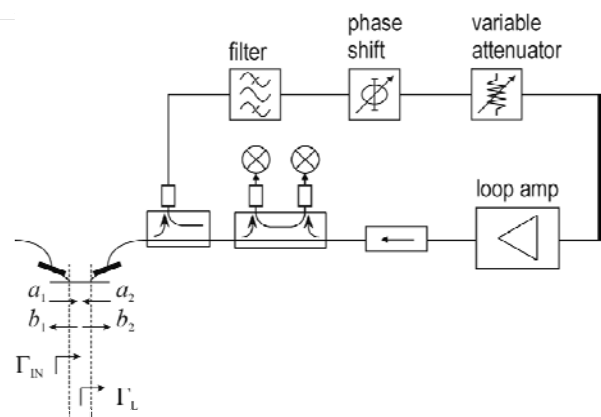
Solutions for tunable loads

Mechanical Tuners



- ▶ Main issue: gamma limitation
 - ▶ Losses cannot be compensated
 - ▶ 2.5 dB losses reduce $|\Gamma|=1$ to $|\Gamma|=0.56$
 - ▶ 0.2 dB losses reduce $|\Gamma|=1$ to $|\Gamma|=0.95$

Active Load – closed loop



- ▶ Main issue: possible oscillations
 - ▶ Reduced risk when losses are reduced

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Load-pull measurements above 60 GHz

Mechanical Tuners

- ▶ Mechanical tuners exist (sold by main vendors) in the millimeter-wave range, up to 110 GHz
 - ▶ require pre-calibration
 - ▶ Including probe and set-up losses, 0.5-0.6 gamma is reachable on-wafer

References

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- ▶ D. W. Baker, et al., "On-wafer load pull characterization of W-band InP HEMT unit cells for CPW MMIC medium power amplifiers," in IEEE MTT-S, Anaheim, CA, USA, Jun. 1999, pp. 1743–1746.
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- ▶ C. Li et al. "Investigation of loading effect on power performance for planar Gunn diodes using load-pull measurement technique," IEEE MWCL, vol. 21, no. 10, pp. 556–558, Oct. 2011.
- ▶ A. Pottrain, et al., "High power density performances of SiGe HBT from BiCMOS technology at W-band," IEEE Electron Device Letters, vol. 33, no. 2, pp. 182–184, Feb. 2012.

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Load-pull measurements above 60 GHz

| Active Loads | References |
|-------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| <ul style="list-style-type: none"> ▶ Open loop active loads combined with <ul style="list-style-type: none"> ▶ 6-port measurements ▶ Mixed signal measurement technique | <ul style="list-style-type: none"> ▶ S. A. Chahine, B. Huyart, E. Bergeault, and L. P. Jallet, "An active millimeter load-pull measurement system using two six-port reflectometers operating in the W-frequency band," IEEE Trans. Instrum. Meas., vol. IM-51, pp. 408–412, Jun. 2002. ▶ L. Galatro, M. Marchetti, M. Spirito, "60 GHz mixed signal active load-pull system for millimeter wave devices characterization," Microwave Measurement Symposium (ARFTG), 2012 80th ARFTG , vol., no., pp.1,6, 29-30 Nov. 2012. |
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Load-pull measurements above 60 GHz

| In Situ Tuners | References |
|---------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|-------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| <ul style="list-style-type: none"> ▶ "In-situ" (integrated) <ul style="list-style-type: none"> ▶ Still gamma limited ▶ Integration required ▶ no real-time | <ul style="list-style-type: none"> ▶ T. V. Heikkil, J. Varis, J. Tuovinen, and G. M. Rebeiz, "W-band RF MEMS double and triple-stub impedance tuners," in IEEE MTT-S Intl. Microwave Symp. Dig., Long Beach, CA, USA, Jun. 2005, pp. 923–926. ▶ Y. Tagro, N. Waldhoff, D. Gloria, S. Boret, G. Dambrine, "In Situ Silicon-Integrated Tuner for Automated On-Wafer MMW Noise Parameters Extraction Using Multi-Impedance Method for Transistor Characterization," IEEE Transactions on Semiconductor Manufacturing, vol.25, no.2, pp.170,177, May 2012 ▶ T. Quemerais, D. Gloria, S. Jan, N. Derrier, P. Chevalier, "Millimeter-wave characterization of Si/SiGe HBTs noise parameters featuring f_T/f_{MAX} of 310/400 GHz," Radio Frequency Integrated Circuits Symposium (RFIC), 2012 IEEE , vol., no., pp.351,354, 17-19 June 2012 |
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94 GHz on-wafer active-loop load-pull system

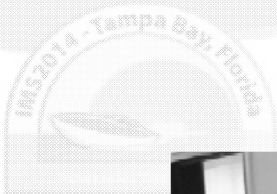
- ▶ Mechanical tuners with pre-calibration: less accurate than real-time
 - ▶ Mechanical tuners with real-time measurements: reduced gamma (0.5 maximum is typical)
 - ▶ In situ tuners: integration with the device / highly developed fabrication capabilities
- ↓
- ▶ Active loads with real-time measurements are a good solution, not yet widely diffused

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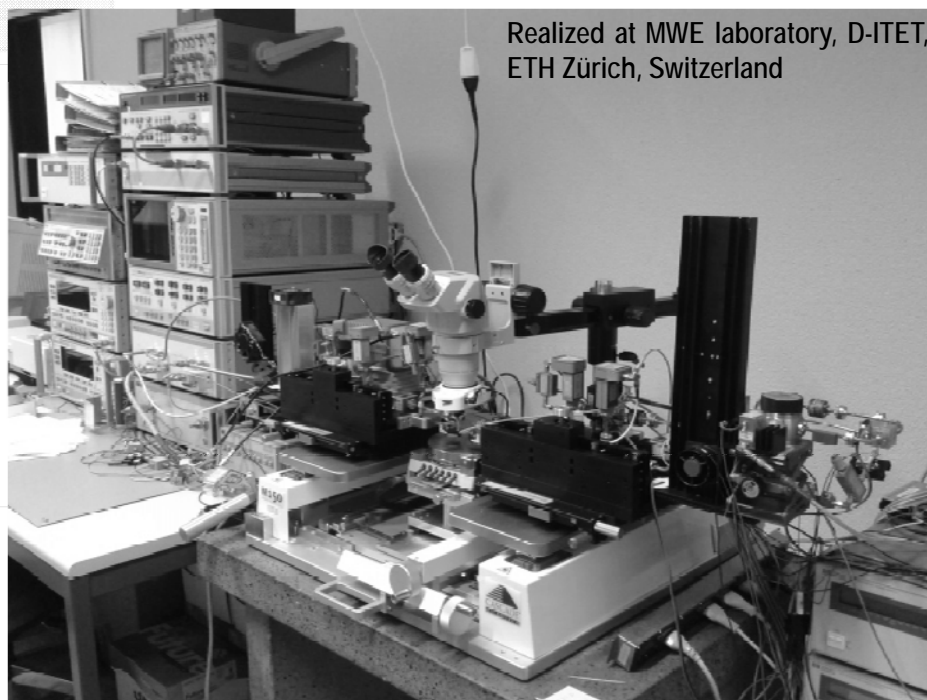
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94 GHz on-wafer active-loop load-pull system



Realized at MWE laboratory, D-ITET,
ETH Zürich, Switzerland

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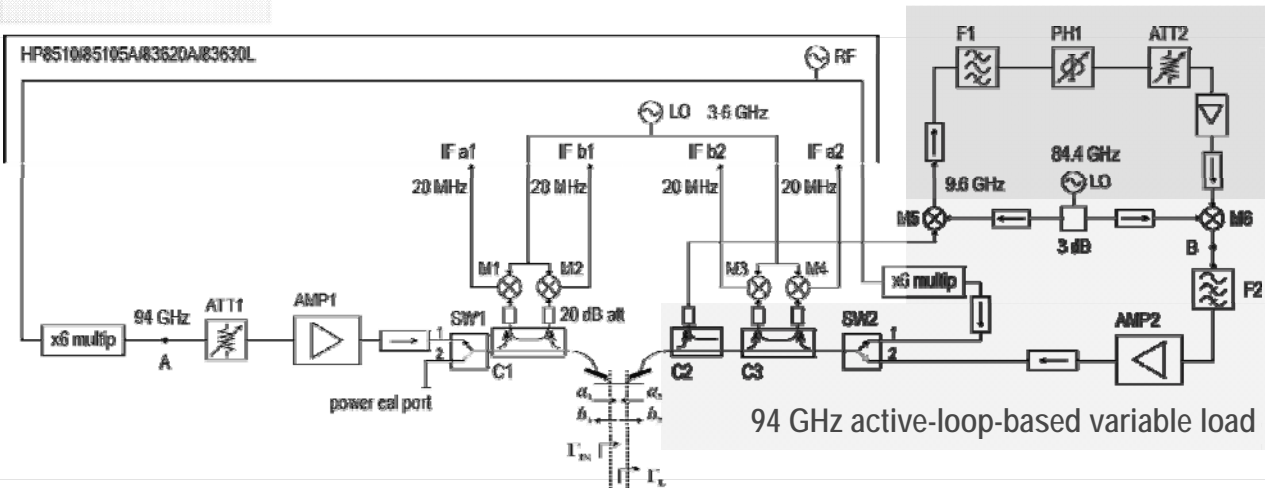
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94 GHz on-wafer active-loop load-pull system

- Simplified block diagram (*)



- **Novelty** – the *down-conversion-based* active loop
 - Similar techniques exist to realize IF loads, at a few hundreds of MHz

(*) V. Teppati, H.-R. Benedikter, et al., "A W-Band On-Wafer Active Load-Pull System based on Down-Conversion Techniques", IEEE Transactions on Microwave Theory and Techniques, Vo. 64, is.1, Jan. 2014, pp. 148-153.

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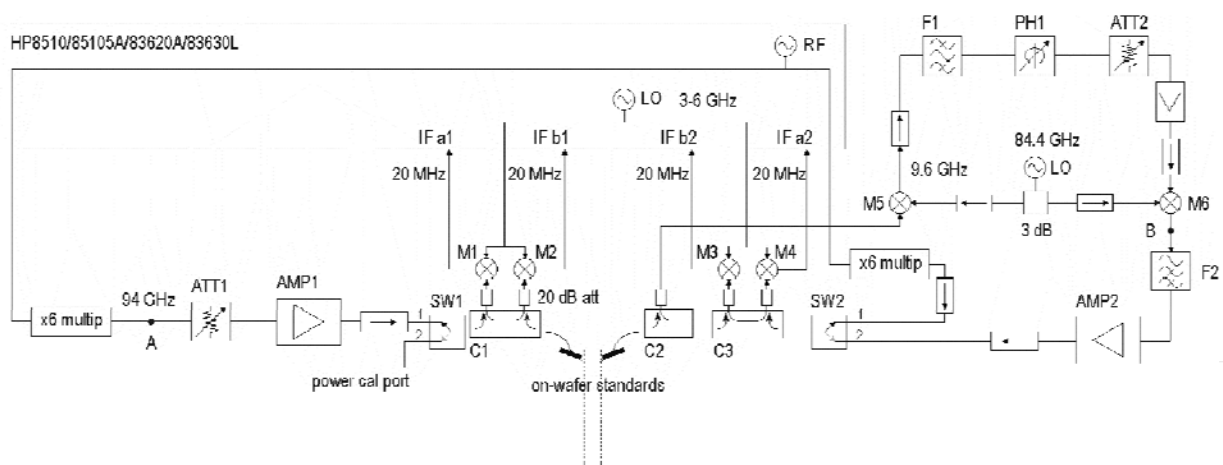
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Load-pull system calibration – step 1

- SW1 and SW2 in position 1
- On-wafer (or calibration substrate) standards are connected and measured



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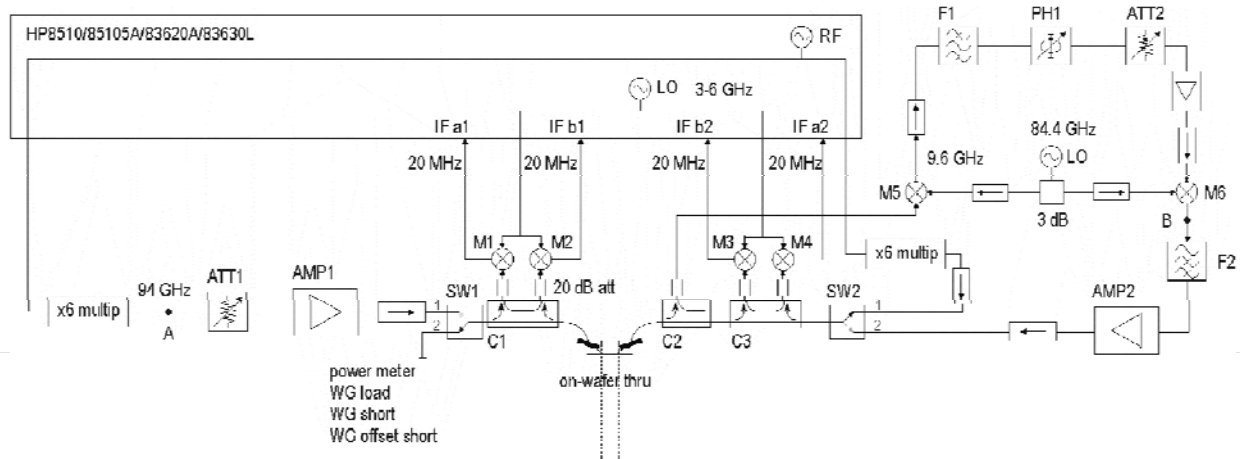
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Load-pull system calibration – step 2

- SW1 in position 2 and SW2 in position 1, thru connection



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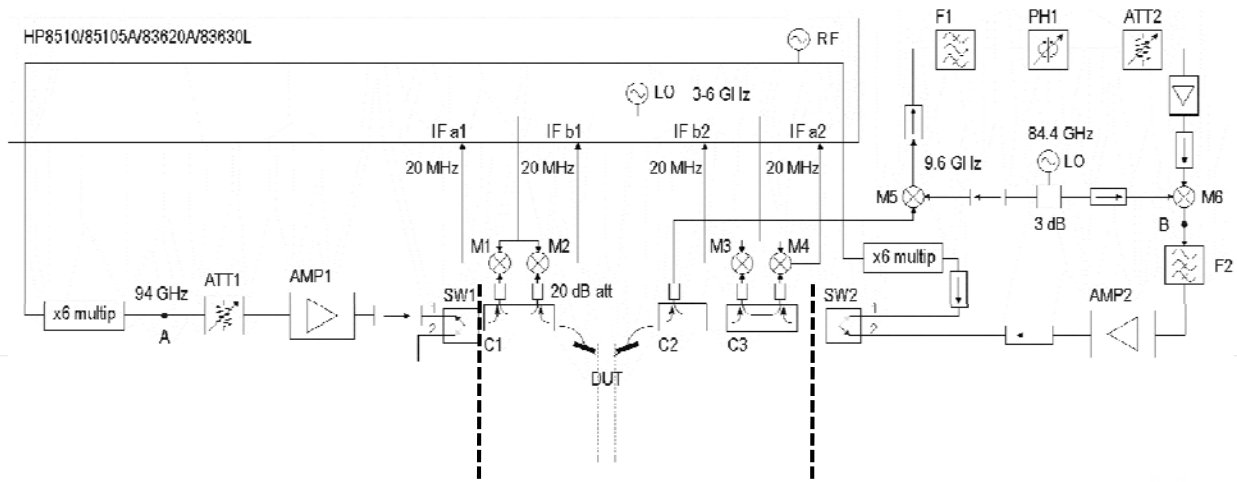
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Measurement Phase

- SW1 in position 1 and SW2 in position 2
- It is possible to modify the set up (add a circulator, or a spectrum analyzer) at the right of reflectometer 2 and at the left of reflectometer 1, without affecting calibration



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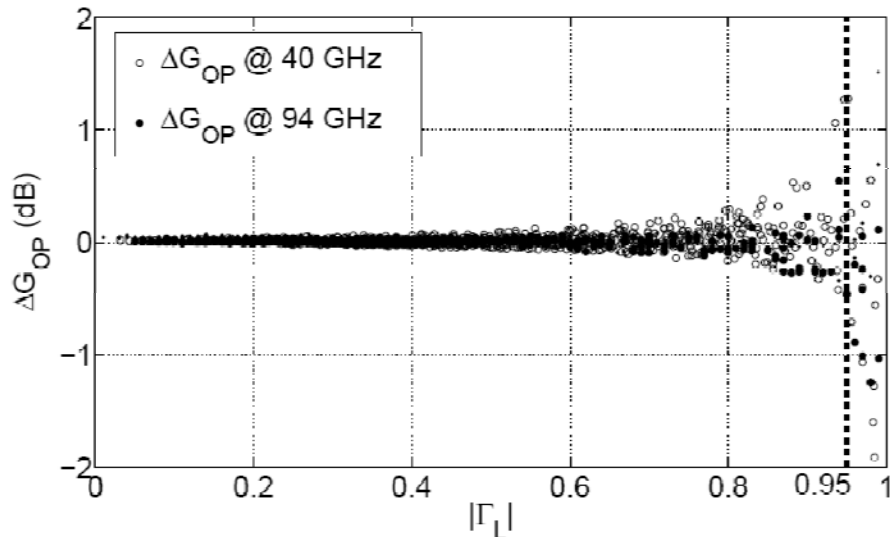
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Residual error comparison

- ▶ A "thru" (on-wafer direct connection) should have 0 dB gain
- ▶ Its gain variation vs. Γ_L is taken as an estimation of the accuracy of the measurement



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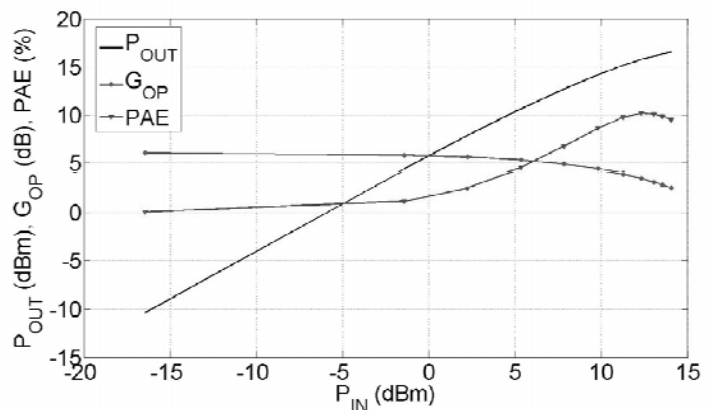
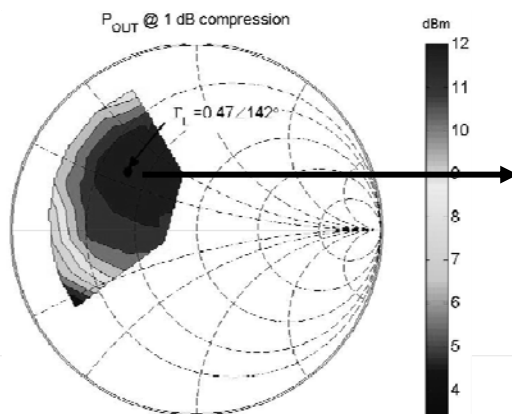
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Measurement examples

- ▶ $0.1 \times 100 \mu\text{m}^2$ GaN HEMT
- ▶ $V_{DS}=5\text{ V}$, $V_{GS}=-3\text{ V}$ (class A)

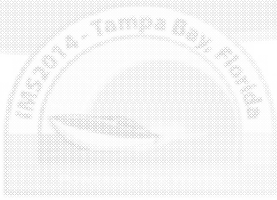


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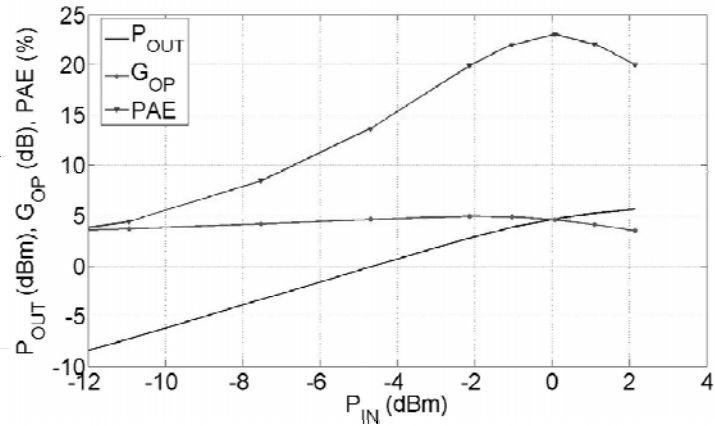
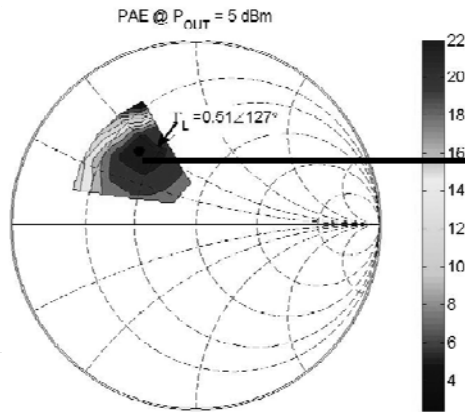
A W-band on-wafer
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Measurement
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Measurement examples

- ▶ $0.3 \times 8.4 \mu\text{m}^2$ InP/GaAsSb DHBT
- ▶ $V_{CE}=1.6\text{ V}$, $V_{BE}=0.75\text{ V}$ (class AB)



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- ▶ Basics of large signal characterization
 - ▶ Mechanical tuners vs. active loads
- ▶ Existing solutions for large signal characterization at high frequencies
- ▶ W-band, down-conversion active loop, on-wafer load-pull system
 - ▶ accuracy
 - ▶ measurement examples

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